High Power RF Applications for Cellular Band with LDMOS Technology



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Agenda

- NXP RF Power Introduction
- LDMOS Product Update
- Drivers and Small Cell
- LDMOS Full Roadmap





NXP 4 Business Units





NXP RF Power Global Presence





RF Power Applications

Cellular Power Amplifiers

- Base stations
- Repeaters
- · From GSM to LTE

ISM (Industrial, Scientific, Medical)

- · Laser/Plasma generator
- Medical
- Particle accelerators
- Industrial heating

Land Mobile Radio

- Handheld
- Vehicle
- Base stations

Cooking Appliances

- · Ovens and ranges
- Counter top appliances
- Commercial
- Consumer

RF Low Power

- Picocells
- Pre-drivers
- Novel PA components

Broadcast

- FM
- VHF TV
- UHF TV

Commercial Avionics

- Distance measuring
- Transponders
- · L- and S-band radars

Aerospace & Defense

- Radar
- Communications
- Electronic warfare

Technology Leadership



True Leader RMS > 1.5

#1 in RF Power for Cellular Infrastructure

#1 in Total RF Power

Source: ABI Research



RF Cellular Investment Focus Areas

mMIMO

- PA modules starting to ramp into mass production
- Continue to drive integration and performance to enable lowest TCO

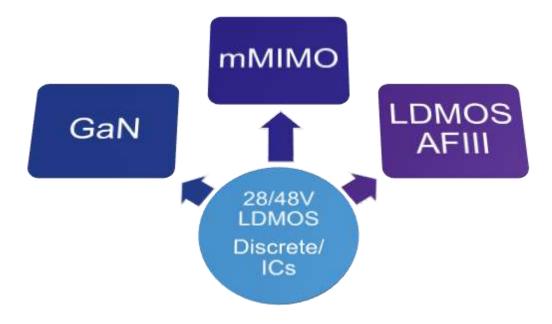
GaN

- Aggressive GaN device technology roadmap
- Internal matching Technology
- Packaging

LDMOS

- New 2-stage 48V drivers and Doherty finals enable single and multi-band solutions below 1GHz
- Full portfolio of industry leading 28V solutions launched and ramping
- Continued development on next generation Doherty drivers and enhanced SBW finals

Cellular Investment Focus





Next Gen Radios: Semiconductor Technology Tool Box

LDMOS 28V

Higher efficiency, integration, and frequency operation

LDMOS 48V

Efficiency and power density of GaN with cost of LDMOS for sub 1GHz high power macro

GaN 48V

Highest efficiency. High band and multiband PA applications

NXP's RF Technology Breadth: From sub-1GHz to mm-wave, and from mW to 10's of W

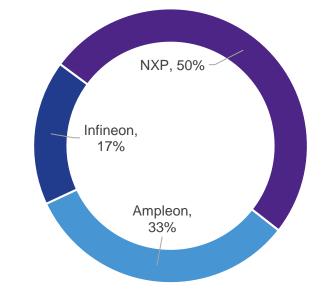




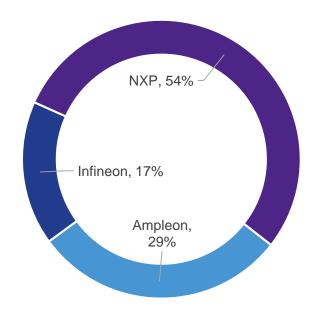
Overall LDMOS Cellular Market Share

2015 RF High Power Cellular: Vendor Shares (Si only)

ABI Estimates



2016 RF High Power Cellular: Vendor Shares (Si Only)



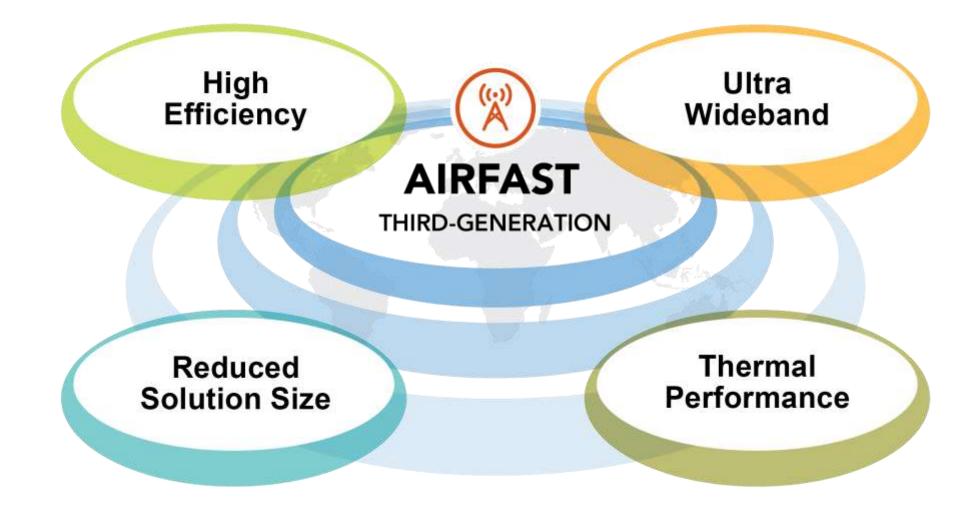
Source: Allied Business Intelligence







NXP Airfast RF Products





LDMOS Airfast Gen 3

- 50% line-up efficiency for 40W and 60W BTS
- Full band operation up to 90MHz
- Best in class thermal performance with Cu flange

A3T18H360W23S



28 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
1805-1880	17.5	53%	55.5

A3T21H450W23S





Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
2110-2200	15.5	49.5%	57.4



LDMOS Airfast Gen 3

A3T18H400W23S

28 V LDMOS Solution



Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
1805-1880	17.2	53%	56.0

A3T18H455W23S



28 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
1805-1880	17.2	52.5%	57.4

A3T21H400W23S



28 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
2110-2200	15.5	51%	56.0

A2T23H200W23S



28 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
2110-2200	15.5	50%	54.5



VHV LDMOS Technology

- Full portfolio of drivers and finals 575 MHz to 960 MHz
- First VHV 2-stage IC driver on the market
- Leading gain and efficiency performance
- Enabling resurgence of sub-1GHz cellular bands with VHV 48V LDMOS

A2V08H525-04N



A2I09VD030N



48 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
575-960	18.7	53%	58.5

48 V LDMOS Solution

Class AB Performance @ 10 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
575-960	34.4	20%	46



VHV LDMOS Technology

A2V09H300-04N

Asto

48 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
720-960	19.5	55%	56.0

A2V07H525-04N



48 V LDMOS Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
575-850	18.5	52%	58.4

A2V09H400-04N



48 V LDMOS Solution

Class AB Performance @ 10 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
720-960	17.5	55%	57.4

A2V09H525-04N

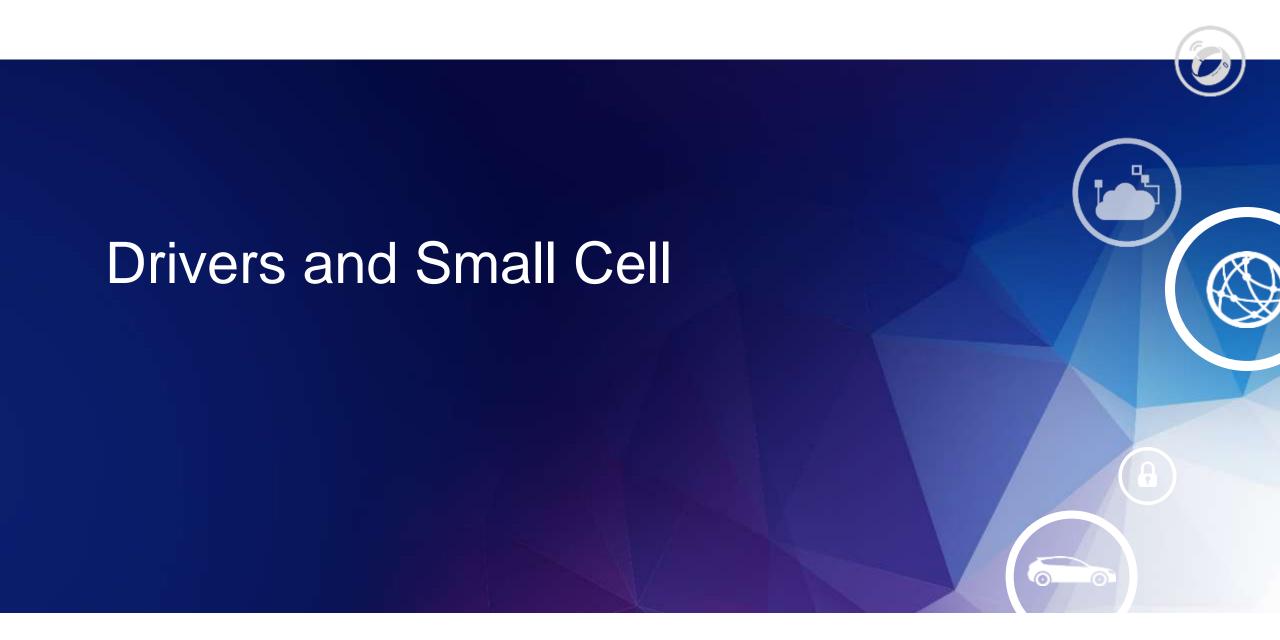




Class AB Performance @ 10 dB OBO

Frequency	Gain	Efficiency	Peak Power
(MHz)	(dB)		(dBm)
720-960	18.5	52%	58.4







Driver and Small Cell Solutions

Solution Type	Package	Summary
Driver & Small Cell Final	TO270-WB	2-stage, 2-path IC solutions with highest power capability and multi-band wideband solutions
Driver	PLD1.5, TO270	1-stage discrete ultra-wideband drivers for macro base stations



Driver and Small Cell Solutions

- 2-stage LDMOS ICs with leading RF performance
- Full line of solutions from 700 MHz to 3800 MHz
- Up to 1GHz RF bandwidth and 400MHz SBW
- Optimized for Class AB and Doherty operation

A2I20D040N



5W IC Final Small Cell Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power	
(MHz)	(dB)		(dBm)	
1400-2300	29.2	46.5%	47.6	

A3I35D025N



5W IC Final Small Cell Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power	
(MHz)	(dB)		(dBm)	
3400-3600	25	35%	42.8	



Driver and Small Cell Solutions

A2I09D015N



5W IC Final Small Cell Solution

Class AB Performance @ 10 dB OBO

Frequency (MHz)	Gain (dB)	Efficiency	Peak Power (dBm)
575-1000	31-33	20%	47.6

A2I08H040N



5W IC Final Small Cell Solution

Doherty Performance @ 8 dB OBO

Frequency	Gain	Efficiency	Peak Power	
(MHz)	(dB)		(dBm)	
728-960	30.7	46%	47.0	

A2I25D025N



5W IC Final Small Cell Solution

Doherty Performance @ 8 dB OBO

Frequency (MHz)	Gain (dB)	Efficiency	Peak Power (dBm)	
2100-2900	28	40%	44.5	

A2I35H060N

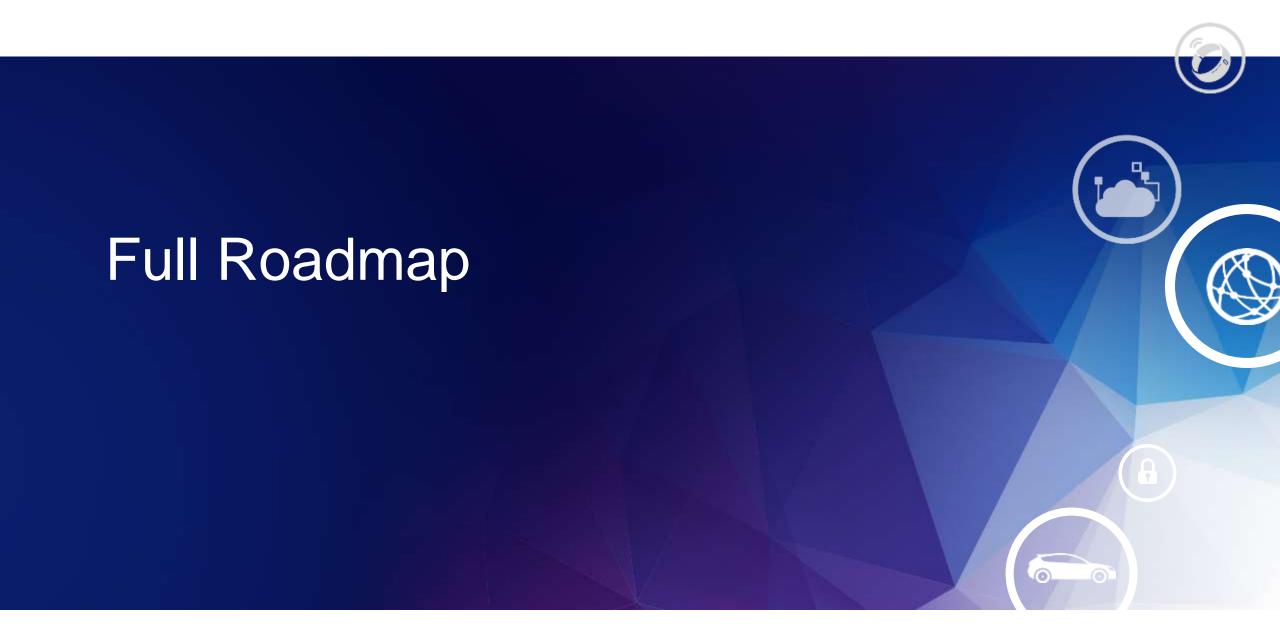


5W IC Final Small Cell Solution

Doherty Performance @ 8 dB OBO

Frequency (MHz)	Gain (dB)	Efficiency	Peak Power (dBm)
3400-3600	24	33%	48.0











575MHz-960MHz Solutions

Macro Base Stations 48V LDMOS

Туре	40W	60W	80W
Final Asym	A2V09H300-04N OM-780-4L Production	A2V09H400-04N OM-780-4L Production A2V07H400-04N OM-780-4L Production	A2V09H300-04N x2 OM-780-4L Production A2V07H525-04N OM-1230-4L Production A2V09H525-04N OM-1230-4L Production
Final Sym	A2T09VD300N TO-270WB-6A Production A2T09VD250N TO-270WB-6A Production A2T09VD250N TO-270WB-6A Production		A2T09VD300N x2 TO-270WB-6A Production
Discrete & IC Driver	A2T08VD020N PQFN8x8 Production	A2109VD030N TO270WB-15 Production PQFN8x8 Production	A2T08VD020N x2 PQFN8x8 Production







720-960MHz Solutions

Micro Base Stations 28V

Туре	5W	10W	20W
Final Discrete	MRF8P9040N TO-270WB-4 Production	MRFE6S9060N TO270-2 Production	A2T07D160W04S NI780-4 Production MRFE6S9060N TO270-2 Production
Final Two Stage IC	MD8IC970N TO-270WB-14 Production A2I08H040N TO-270WB-15 Production	MDE6IC9120N TO-270WB-16 Production	MDE6IC9120N TO-270WB-16 Production
Discrete Driver	MMG3006N QFN4x4 Production	A2T27S007N DFN 4X6 Production AFT27S006 PLD – 1.5W Production	A2T27S007N DFN 4X6 Production AFT27S006 PLD – 1.5W Production



720-960MHz Solutions

Macro Base Stations 28V

Туре	40W	60W	80W
Final Discrete	AFT09S200W02N x2 OM-780-2 Production	AFT09S200W02N/AFT09S282N OM-780-2/OM-780-2 Production/ Production	AFT09S200W02N x3 OM-780-2 Production AFT09S220-02N/AFT09S282N OM-780-2/OM-780-2 Production/ Production
Final HiP	A2T07H310-24S NI-1230S-4L2L Production A2T09D400-23N OM-1230S-4L2S Production A2T09D400-23N OM-1230S-4L2S Production	A2T09H360W23S NI-1230S-4L2S Now	A2T07H310-24S x2 NI-1230S-4L2L Production AFT09H310-03S x2 NI-1230S-4S Production
Two Stage IC Driver	MW7IC915N PQFN8x8 Production MW8IC925N x2 TO-270WB-14 Production	MW7IC930N TO-270WB-14 Production MD8IC925N TO-270WB-14 Production	A2I08H040N TO-270WB-17 Production
Discrete Driver	A2T27S020N TO-270-2 Production AFT27S010N x2 PLD1.5W Production	A2T27S020N TO-270-2 Production MRF8P9040N TO-270WB-4 Production	MRF8P9040N TO-270WB-4 Production







1400-2000 MHz Solutions

Micro Base Stations 28V

Туре	5W	10W	15W-20W
Final Dual path/ HiP		A2T18H100-25S NI780-4L4S Production	A2T20H160W04N OM-780-4L Production A2T18H160-24S NI-780-4L2L Production AFT20P140-4WN OM-780-4 Production
Final 2 stage IC	A2I20D040N A2I20H060N TO-270WB-17 TO-270WB-15 Production Production A2I22D050N TO-270WB-15 Production	A2I20H080N TO-270WB-15 Production	
Discrete Driver	MMG3006N QFN4x4 Production A2T27S007N DFN 4X6 Production	MMG3006N QFN4x4 Production A2T27S007N DFN 4X6 Production	MMG3006N QFN4x4 Production A2T27S007N DFN 4X6 Production
2 Stage IC Driver	MMZ25332B QFN3x3 Production	MMZ25332B x2 QFN3x3 Production	MD7IC2012N TO-270WB-14 Production MD7IC1812N TO-270WB-14 Production



1400-2000 MHz Solutions

Туре	40V	V	60\	W	80'	W
Final HiP	A2T20H330W24N OM-1230-4L2L Production A3T18H360W23S ACP-1230S-4L2S Production	A3T18H400W23S ACP-1230S-4L2S Production	A3T18H455W23S ACP-1230S-4L2S Production A2T18H455W23N OM-1230-4L2S Production	A2T14H450-23N OM-1230-4L2S Production	A3T18H360W23S X2 ACP-1230S-4L2S Production A3T18H400W23S X2 ACP-1230S-4L2S Production	
Final Asym			A2T18S160W31S/ AF NI-780S-2L2LA/NI-780 Production /Producti	OS-2L2LA	A2T18S260-12S x3 NI-780-2L2L Production	A2T18S262W12N x3 OM-880X-2L2L Production
Final Sym	A2T18S165-12S x2 NI-780S-2L2L Production	AFT18P350-4S2L NI-1230-4L2L Production	AFT18S230S x2 NI-780S-2L4S Production		AFT18S290-13S x2 NI-880S-2L4S Production	AFT18P350-4S2L x2 NI1230-4L2L Production
IC Driver	A2I20D020N TO-270WB-17 Production		A2I20D040N TO-270WB-17 Production		A2I20H080N TO-270WB-15 Production	A2I22D050N TO-270WB-15 Production
Discrete Driver	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production	AFT27S010N x2 PLD1.5W Production	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production	AFT27S010N x2 PLD1.5W Production	AFT20P060-4N OM-780-4 Production	A2T27S020N x2 TO-270-2 Production







Line Up Micro Base Stations 28Volts

Туре	5W	10W	20W
Final Discrete	AFT20P060-4N OM-780-4 Production	A2T21H100-25S NI780-4L4S Production	A2T20H160W04N OM-780-4L Production
Final 2 Stage IC	A2I20D040N TO-270WB-17 Production A2I20H060N TO270WB-15 Production	A2/20H080N TO-270WB-15 Production	
Discrete Driver	A2T27S007N DFN 4X6 Production AFT27S006N PLD1.5W Production MMG15241H SOT-89 Production	A2T27S007N DFN 4X6 Production AFT27S006N PLD1.5W Production AFT27S010N PLD1.5W Production	A2T27S007N DFN 4X6 Production AFT27S006N PLD1.5W Production AFT27S010N PLD1.5W Production
2 Stage IC Driver	MMZ25332B QFN3x3 Production	MMZ25332B x2 QFN3x3 Production	A2I25D012N TO-270WB-15 Production MD7IC2012N TO-270WB-14 Production



2100 MHz Solutions Line Up Macro Base Stations 28Volts

Type	40W	60W	80W
Final HiP	A3T21H360W23S ACP-1230S-4L2S Production A2T21H360-24N OM-1230-4L2S Production	A3T21H450W23S ACP-1230S-4L2S Production	A3T21H360W23S x2 ACP-1230S-4L2S Production
Final Asym	A2T21S140W02S/A2T21S220W02 NI780-2L/NI-780-2L Production/Production	A2T21S160-12S/A2T21S260-12S NI-780S-2L2L/NI-780S-2L2L Production / Production	A2T21S260W12N x3 OM-880X-2L2L Production
Final Sym		AFT21S240-12S x2 NI-880XS-2L2L Production	AFT21S240-12S x2 NI-880XS-2L2L Production
IC Driver	A2I25D025N TO-270WB-17 Production A2I20D020N TO-270WB-17 Production	A2I20D040N TO-270WB-17 Production	A2I22D050N TO-270WB-15 Production A2I20H080N TO-270WB-15 Production
Discrete Driver	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production AFT27S010N x2 PLD1.5W Production	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production AFT27S010N x2 PLD1.5W Production	AFT20P060-4N OM-780-4 Production A2T27S020N x2 TO-270-2 Production







Line Up Macro Base Stations 28Volts

Туре	5W	20W
Final Discrete		A2T23H160-24S NI-780S-4L2L Production
Final 2 stage IC	A2I25H060N TO-270WB-17 Production	
Discrete Driver	MMG15241H SOT-89 Production	A2T27S007N DFN 4X6 Production AFT27S006 PLD1.5W Production AFT27S010N PLD1.5W Production
2 Stage IC Driver	MMZ2332B DFN 3X3 Production	A2I25D012N TO-270WB-15 Production



Line Up Macro Base Stations 28Volts

Type	40W	60W
Final HiP	A2T23H200W23S ACP-1230-4L2S Production	A2T23H300-24S NI-1230-4S2L Production
IC Driver	A2I25D025N TO-270WB-15 Production	A2I25H060N TO-270WB-17 Production
Discrete Driver	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production AFT27S010N x2 PLD1.5W Production	A2T27S020N x2 TO-270-2 Production AFT20S015N x2 TO-270-2 Production







Line Up Micro Base Stations 28Volts

Type	5W	10W	20W
Final HiP	AFT26HW050S NI-780-8S Production		A2T26H160-24S NI780-4L2L Production A2T26H165-24S NI780-4L2L Production
Final Sym		AFT26P100-4WS NI-780-4S Production	
Final 2 stage IC	MD7IC2755N TO-270WB-14 Production A2I25H060N TO270WB-17 Production	A2I25H060N x2 T0270WB-17 Production	
Discrete Driver	A2T27S007N DFN 4X6 Production AFT27S006N PLD1.5W Production MMG15241H SOT-89 Production	AFT20S015N TO-270-2 Production AFT27S010N PLD1.5W Production	A2T27S020N TO-270-2 Production AFT20S015N TO-270-2 Production AFT27S010N x2 PLD1.5W Production
2 Stage IC Driver	MMZ25332B QFN3x3 Production	A2I25D012N TO-270WB-15 Production	A2I25D025N TO-270WB-17 Production



Line Up Macro Base Stations 28Volts

Туре	30W	40-60 W
Final HiP	AFT26H250-24S NI1230-4L2L Production AFT26H200W03S/-24S NI-1230-4S /NI-1230-4L2L Production	A2T26H300-24S NI1230-4L2L Production AFT26H250-24S NI1230-4L2L Production
IC Driver	A2I25D025N TO-270WB-17 Production	A2I25H060N TO270WB-17 Production
Discrete Driver	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production AFT27S010N x2 PLD1.5W Production	A2T27S020N TO-270-2 Production AFT20S015N x2 TO-270-2 Production AFT27S010N x2 PLD1.5W Production



Line Up Micro Base Stations 28Volts

Туре	1-2W	5W	10W	15-20W
Finals	A3I35D012N TO-270WB-17 Now AFT27S006N PLD1.5W Production	A3/35D025N TO-270-WB-17 Now A3/35H060N TO-270-WB-17 Production	A2I35H060N x2 TO-270-WB-17 Production	
Drivers			A2T27S007N DFN 4X6 Production AFT27S006N PLD1.5W Production	A3I35D012N TO-270WB-17 Now AFT27S010N PLD1.5W Production





SECURE CONNECTIONS FOR A SMARTER WORLD